

IR Laser Diode

Application

Industrial use / Biomedical

Property

Wavelength $\lambda = 785\text{nm}$

Output Power = 50mW

Package Type = $\phi 5.6\text{mm}$

Introduction

Egismos currently markets AlGaAs infrared laser diodes in the 780nm ~ 1550nm wavelengths range. The low operating current and high temperature of the laser diodes are achieved through using misoriented substrate and MQW (Strain compensated) active layer.

Egismos laser diodes are highly rated in a broad range of applications including, but not limited to, laser pointers, green lasers, blue laser DVD, laser barcode scanners, diode laser equipments, medical instruments and aerospace applications.



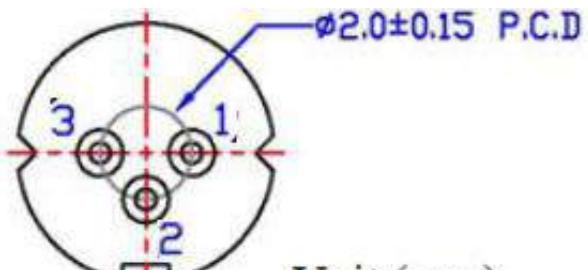
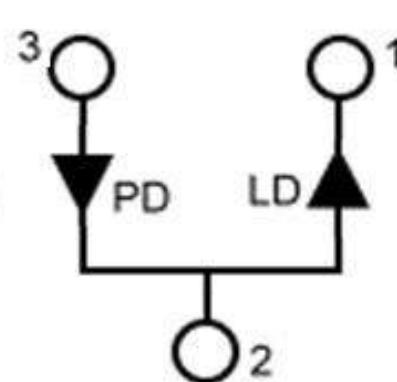
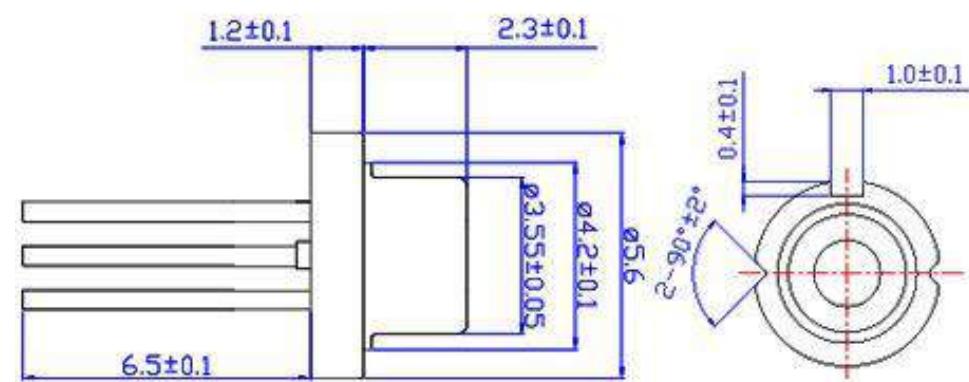
IR Laser Diode Key features

Absolute Maximum Rating at $T_c=25^\circ\text{C}$				
Items	Symbols	Values	Unit	
Optical Output Power	$P_o(\text{CW})$	50	mW	
Reverse Voltage	V	2	V	
Operating Temperature	T_o	-10~+60	°C	
Storage Temperature	T_s	-10~+70	°C	

Electrical and Optical Characteristics at $T_c=25^\circ\text{C}$

Item	Symbols	Min	Typ.	Max.	Unit	Condition
Optical Output Power	P_o	-	-	50	mW	-
Threshold Current	I_{th}	-	25	40	mA	-
Operating Current	I_{op}	-	75	100	mA	$P_o=50\text{mW}$
Operating Voltage	V_{op}	-	2.0	2.8	V	$P_o=50\text{mW}$
Peak Wavelength	λ_p	775	785	795	nm	$P_o=50\text{mW}$

Beam Divergence	$\theta//$	7	9	12	deg	Po=50mW
	$\theta\perp$	17	22	27	deg	Po=50mW

Electrical Connection(Bottom View)	Package Type
 Unit (mm)	
Package Drawing	
	

Specifications are subject to change without notice.

